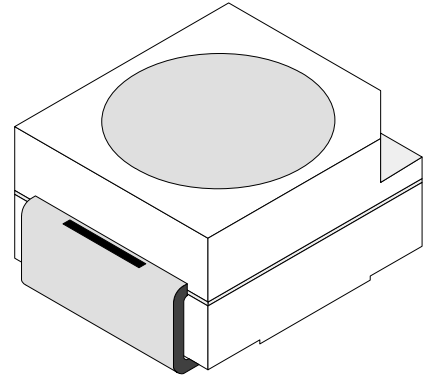


## Low Current SMD LED

Color	Type	Technology	Angle of Half Intensity $\pm\varphi$
High efficiency red	TLMT3100	GaAsP on GaP	60°

### Description

These new devices have been designed to meet the increasing demand for low current SMD LEDs. The package of the TLMT3100 is the P-LCC-2 (equivalent to a size B tantalum capacitor). It consists of a lead frame which is embedded in a white thermoplast. The reflector inside this package is filled up with clear epoxy.



94 8553

### Features

- SMD LED with exceptional brightness
- Compatible with automatic placement equipment
- EIA and ICE standard package
- Compatible with infrared, vapor phase and wave solder processes according to CECC
- Available in 8 mm tape
- Low profile package
- Non-diffused lens: excellent for coupling to light pipes and backlighting
- Very low power consumption
- Luminous intensity ratio in one packaging unit  
 $I_{Vmax}/I_{Vmin} \cong 2.0$

### Applications

Automotive: backlighting in dashboards and switches  
 Telecommunication: indicator and backlighting in telephone and fax  
 Indicator and backlight for audio and video equipment  
 Indicator and backlight for battery driven equipment  
 Small indicator for outdoor applications  
 Indicator and backlight in office equipment  
 Flat backlight for LCDs, switches and symbols  
 General use

### Absolute Maximum Ratings

$T_{amb} = 25^{\circ}\text{C}$ , unless otherwise specified

#### TLMT3100

Parameter	Test Conditions	Symbol	Value	Unit
Reverse voltage		$V_R$	6	V
DC forward current		$I_F$	7	mA
Surge forward current	$t_p \leq 10 \mu\text{s}$	$I_{FSM}$	0.5	A
Power dissipation	$T_{amb} \leq 90^{\circ}\text{C}$	$P_V$	20	mW
Junction temperature		$T_j$	100	$^{\circ}\text{C}$
Operating temperature range		$T_{amb}$	-40 to +100	$^{\circ}\text{C}$
Storage temperature range		$T_{stg}$	-55 to +100	$^{\circ}\text{C}$
Soldering temperature	$t \leq 5 \text{ s}$	$T_{sd}$	260	$^{\circ}\text{C}$
Thermal resistance junction/ambient	mounted on PC board (pad size > 16 mm <sup>2</sup> )	$R_{thJA}$	500	K/W

### Optical and Electrical Characteristics

$T_{amb} = 25^{\circ}\text{C}$ , unless otherwise specified

#### High efficiency red (TLMT3100)

Parameter	Test Conditions	Type	Symbol	Min	Typ	Max	Unit
Luminous intensity <sup>2)</sup>	$I_F = 2\text{ mA}$		$I_V$	0.25	2.5		mcd
Dominant wavelength	$I_F = 2\text{ mA}$		$\lambda_d$	612		625	nm
Peak wavelength	$I_F = 2\text{ mA}$		$\lambda_p$		635		nm
Angle of half intensity	$I_F = 2\text{ mA}$		$\phi$		$\pm 60$		deg
Forward voltage	$I_F = 2\text{ mA}$		$V_F$		2.2	2.9	V
Reverse voltage	$I_R = 10\ \mu\text{A}$		$V_R$	6	15		V
Junction capacitance	$V_R = 0, f = 1\text{ MHz}$		$C_j$		50		pF

<sup>2)</sup> in one Packing Unit  $I_{V\text{Min.}}/I_{V\text{Max.}} \leq 2$

### Typical Characteristics ( $T_{amb} = 25^{\circ}\text{C}$ , unless otherwise specified)

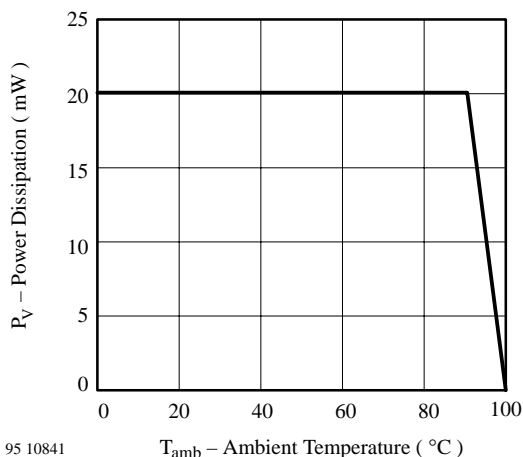


Figure 1. Power Dissipation vs. Ambient Temperature

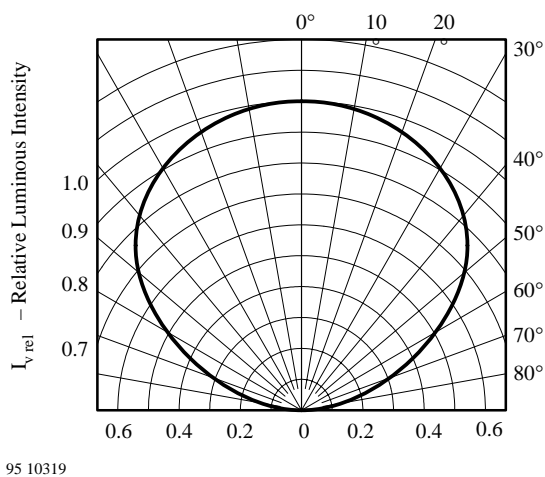


Figure 3. Rel. Luminous Intensity vs. Angular Displacement

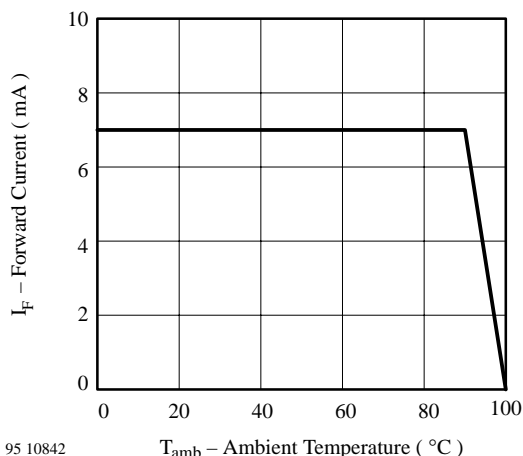


Figure 2. Forward Current vs. Ambient Temperature

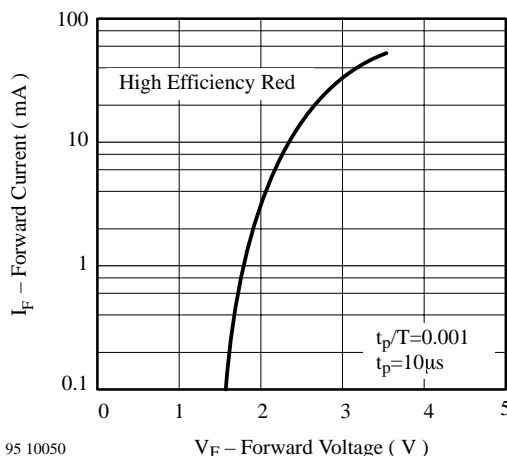


Figure 4. Forward Current vs. Forward Voltage

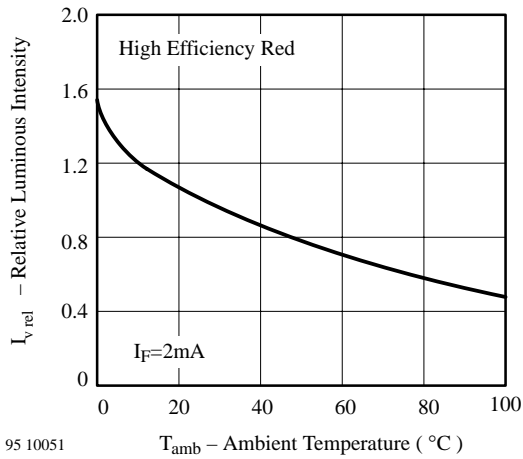


Figure 5. Rel. Luminous Intensity vs. Ambient Temperature

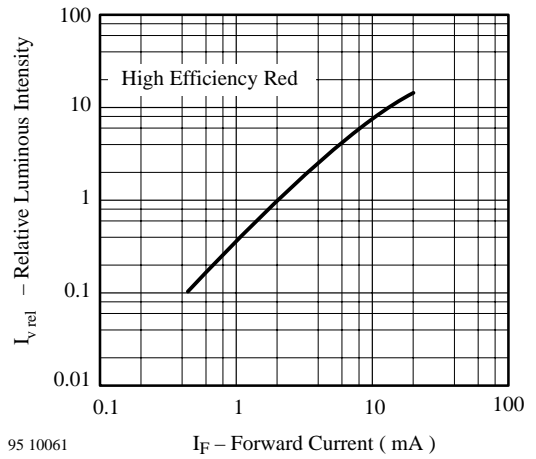


Figure 7. Relative Luminous Intensity vs. Forward Current

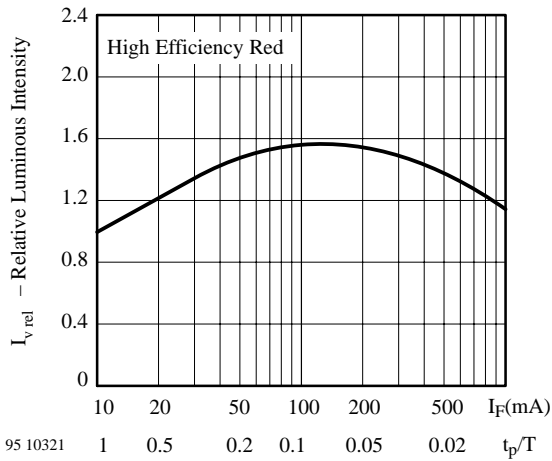


Figure 6. Rel. Lumin. Intensity vs. Forw. Current/Duty Cycle

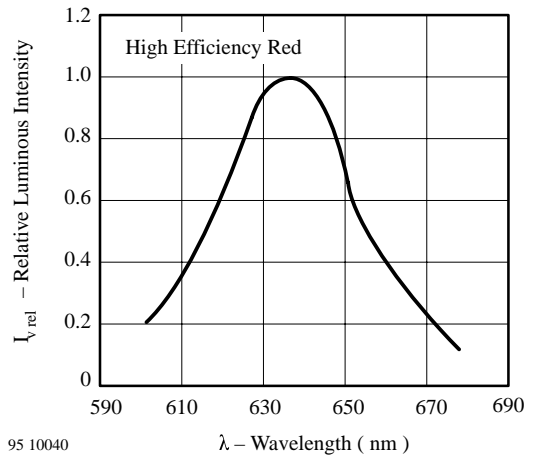
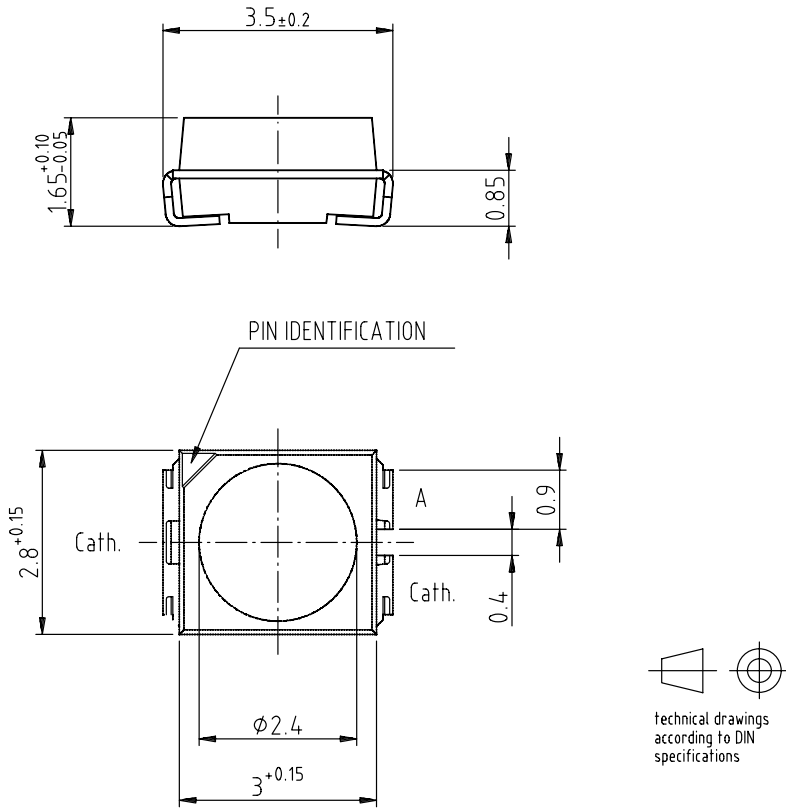
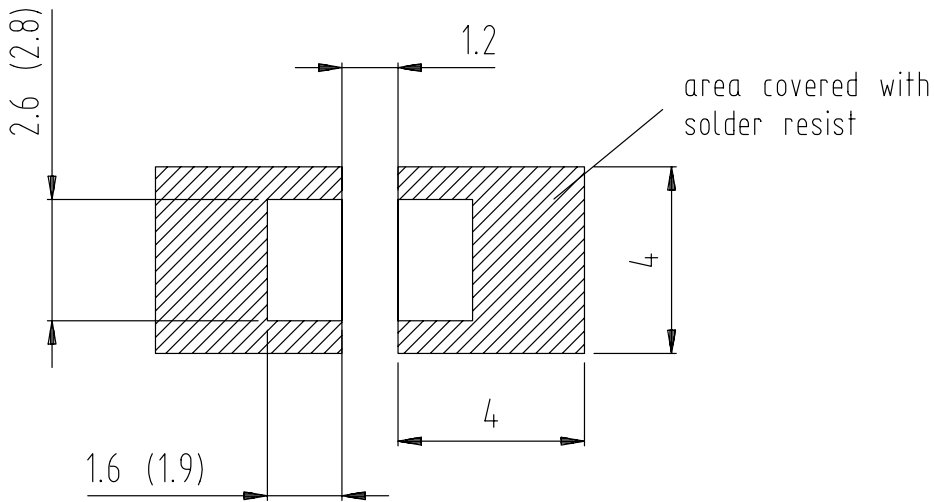


Figure 8. Relative Luminous Intensity vs. Wavelength

### Dimensions in mm



### PCB Layout in mm



Dimensions: IR and Vaporphase  
( Wave Soldering )

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## **Ozone Depleting Substances Policy Statement**

It is the policy of **Vishay Semiconductor GmbH** to

1. Meet all present and future national and international statutory requirements.
2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

**Vishay Semiconductor GmbH** has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively
2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA
3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

**Vishay Semiconductor GmbH** can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

**We reserve the right to make changes to improve technical design and may do so without further notice.**

Parameters can vary in different applications. All operating parameters must be validated for each customer application by the customer. Should the buyer use Vishay-Telefunken products for any unintended or unauthorized application, the buyer shall indemnify Vishay-Telefunken against all claims, costs, damages, and expenses, arising out of, directly or indirectly, any claim of personal damage, injury or death associated with such unintended or unauthorized use.

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